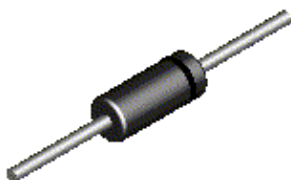


## 1N4150 / FDLL4150



DO-35



LL-34

THE PLACEMENT OF THE EXPANSION GAP  
HAS NO RELATIONSHIP TO THE LOCATION  
OF THE CATHODE TERMINAL

COLOR BAND MARKING		
DEVICE	1ST BAND	2ND BAND
FDLL4150	BLACK	ORANGE

### High Conductance Ultra Fast Diode

Sourced from Process 1R. See MMBD1201-1205 for characteristics.

#### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$W_{IV}$	Working Inverse Voltage	50	V
$I_O$	Average Rectified Current	200	mA
$I_F$	DC Forward Current	400	mA
$i_f$	Recurrent Peak Forward Current	600	mA
$i_{f(surge)}$	Peak Forward Surge Current		
	Pulse width = 1.0 second	1.0	A
	Pulse width = 1.0 microsecond	4.0	A
$T_{stg}$	Storage Temperature Range	-65 to +200	°C
$T_J$	Operating Junction Temperature	175	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**NOTES:**

- 1) These ratings are based on a maximum junction temperature of 200 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		1N / FDLL 4150	
$P_D$	Total Device Dissipation Derate above 25°C	500	mW
		3.33	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W

## High Conductance Ultra Fast Diode

(continued)

1N4150 / FDLL4150

### Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
B <sub>V</sub>	Breakdown Voltage	I <sub>R</sub> = 5.0 μA	75		V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 50 V V <sub>R</sub> = 50 V, T <sub>A</sub> = 150°C		100 100	nA μA
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 1.0 mA I <sub>F</sub> = 10 mA I <sub>F</sub> = 50 mA I <sub>F</sub> = 100 mA I <sub>F</sub> = 200 mA	540 660 760 820 0.87	620 740 860 920 1.0	mV mV mV mV V
C <sub>O</sub>	Diode Capacitance	V <sub>R</sub> = 0, f = 1.0 MHz		2.5	pF
T <sub>RR</sub>	Reverse Recovery Time	I <sub>F</sub> = I <sub>R</sub> = 10 mA-200 mA, R <sub>L</sub> = 100Ω I <sub>F</sub> = I <sub>R</sub> = 200 mA-400 mA, R <sub>L</sub> = 100Ω		4.0 6.0	nS nS
T <sub>FR</sub>	Forward Recovery Time	I <sub>F</sub> = 200 mA, V <sub>FR</sub> = 1.0 V		10	nS

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FACT™	QS™
FACT Quiet Series™	Quiet Series™
FAST®	SuperSOT™-3
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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## PRODUCT STATUS DEFINITIONS

### Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.